



Vishay General Semiconductor

## **Dual Common-Cathode Schottky Rectifier**



MAJOR RATINGS AND CHARACTERISTICS					
I <sub>F(AV)</sub>	40 A				
V <sub>RRM</sub>	35 V to 60 V				
I <sub>FSM</sub>	400 A				
V <sub>F</sub>	0.60 V, 0.62 V				
T <sub>j</sub> max.	150 °C				

#### **FEATURES**

· Guardring for overvoltage protection



· Lower power losses, high efficiency

· Low forward voltage drop

· High forward surge capability

· High frequency operation

• Solder Dip 260 °C, 40 seconds

• Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, free-wheeling diodes, dc-to-dc converters or polarity protection application.

### **MECHANICAL DATA**

Case: TO-247AD (TO-3P)

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002B and JESD22-B102D E3 suffix for commercial grade

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER		MBR4035PT	MBR4045PT	MBR4050PT	MBR4060PT	UNIT		
Maximum repetitive peak reverse voltage	$V_{RRM}$	35	45	50	60	V		
Maximum working peak reverse voltage	$V_{RWM}$	35 45 50 60		60	V			
Maximum DC blocking voltage	$V_{DC}$	DC 35 45 50 60		60	V			
Maximum average forward rectified current at $T_C = 125$ °C	I <sub>F(AV)</sub>	40 A						
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	400 A				Α		
Peak repetitive reverse surge current per diode (1)	I <sub>RRM</sub>	2.0 1.0			Α			
Voltage rate of change at (rated V <sub>R</sub> )	dv/dt	10000 V/µ			V/µs			
Operating junction temperature range	TJ	- 65 to + 150 °C			°C			
Storage temperature range	T <sub>STG</sub>	- 65 to + 175 °C			°C			

### Note:

(1) 2.0  $\mu$ s pulse width, f = 1.0 kHz

Document Number: 88679 www.vishay.com Revision: 25-May-07

## MBR4035PT thru MBR4060PT

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS	SYMBOL	MBR4035PT	MBR4045PT	MBR4050PT	MBR4060PT	UNIT	
Maximum instantaneous forward voltage per diode (1)	$\begin{split} I_F &= 20 \text{ A},  T_C = 25 \text{ °C} \\ I_F &= 20 \text{ A},  T_C = 125 \text{ °C} \\ I_F &= 40 \text{ A},  T_C = 25 \text{ °C} \\ I_F &= 40 \text{ A},  T_C = 125 \text{ °C} \end{split}$	V <sub>F</sub>	0.70 0.60 0.80 0.75		-	72 62 - -	>	
Maximum instantaneous reverse current at rated DC blocking voltage per diode (1)	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C	I <sub>R</sub>	1.0 100			mA		

#### Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR4035PT	MBR4045PT	MBR4050PT	MBR4060PT	UNIT
Maximum thermal resistance from junction to case per diode	$R_{ heta JC}$	1.2			°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-247AD	MBR4045PT-E3/45	6.13	45	30/Tube	Tube		

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

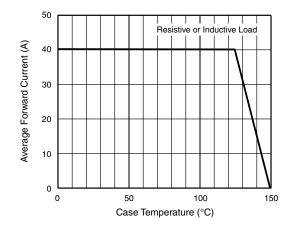


Figure 1. Forward Current Derating Curve

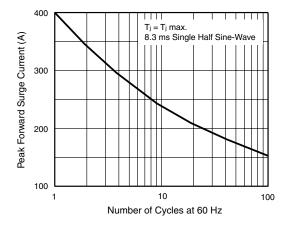


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode





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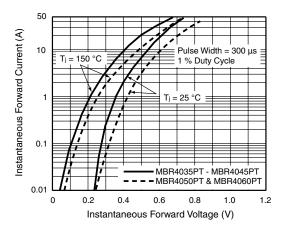


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

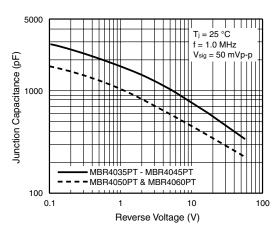


Figure 5. Typical Junction Capacitance Per Diode

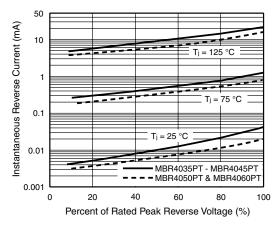


Figure 4. Typical Reverse Characteristics Per Diode

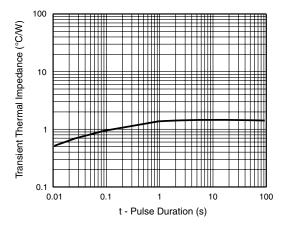
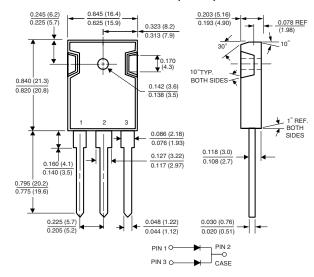


Figure 6. Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

### TO-247AD (TO-3P)



Document Number: 88679
Revision: 25-May-07

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## **Legal Disclaimer Notice**



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Document Number: 91000 www.vishay.com Revision: 08-Apr-05